

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In application of

Takashi KOBAYASHI et al.

Serial No.: 10/646,590

Group Art Unit: 2811

Filed: August 22, 2003

Examiner:

For: SEMICONDUCTOR DEVICE

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INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
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Sir:

Pursuant to 37 C.F.R. §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached Form PTO-1449. Copies of the references listed on Form PTO-1449 are attached.

It is respectfully requested that the information be expressly considered during the prosecution of this application, that these references be made of record therein and appear among the "References Cited" on any patent to issue therefrom, and that an initialed copy of the PTO-1449 be returned to the undersigned.

Respectfully submitted,

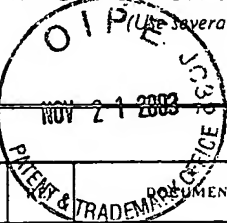
Date: 11-19-03

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Marc A. Rossi
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Attorney Docket No.: FUJI:200A

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)



Docket Number (Optional)

FUJI:200A

Application Number

10/646,590

Applicant(s)

Takashi KOBAYASHI et al.

Filing Date

August 22, 2003

Group Art Unit

2811

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
US	4,412,242	10/83	Herman et al.	357	52	
US	4,399,449	8/83	Herman et al.	357	53	
US	5,338,961	8/94	Lidow et al.	257	342	
US	6,476,456	11/02	Boden, Jr.	257	486	
US	6,114,726	9/00	Barkhordarian	257	341	
US	4,809,045	2/89	Yilmaz	357	23.4	
US	5,028,548	7/91	Nguyen	437	15	
US	5,510,634	4/96	Okabe et al.	257	139	

FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
EP	0 671 769 A2	9/95	EPO				
EP	0 749 163 A2	12/96	EPO				
EP	0 115 093 A2	8/84	EPO				
GB	2 161 649 A	1/86	GB				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	"Optimization and Surface Charge Sensitivity of High-Voltage Blocking Structures with Shallow Junctions"; Hamza Yilmaz; July 1991; IEEE Transactions on Electron Devices, Vol. 38, No. 7; pages 1666-1675.
	"A Parametric Study of Power Mosfets"; Chenming Hu; Proceedings of the Conference of Rec. Power Electronics Specialists, 1979 IEEE; pages 385-395.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.